NSN 5961-01-211-2641



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-211-2641 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 4.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 300.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Specification Data:

81349-mil-s-19500/399 government specification

Demilitarization:

Voc. domil/mli

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